

SS22A THRU SS225A

RoHS

Technical Data Data Sheet N1816, Rev. A SS22A THRU SS225A SCHOTTKY RECTIFIER

SMA

Features

- Schottky Brrier Chip
- Low Power Loss, High Efficiency
- Ideally Suited for Automatic Assembly
- Surge Overload Rating to 50A Peak
- Plastic Case Material has UL Flammability Classification Rating 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: SMA, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-750, Method 2026 guaranteed
- Polarity: Color band denotes cathode end
- Mounting Position: Any

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Type Number	Symbol	SS 22A	SS 23A	SS 24A	SS 245A	SS 25A	SS 26A	SS 28A	SS 210A	SS 215A	SS 220A	SS 225A	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	20	30	40	45	50	60	80	100	150	200	250	V
RMS Reverse Voltage	V _{RMS}	14	21	28	31	35	42	56	70	105	140	175	V
Average forward rectified output current $@T_A = 90^{\circ}C$	lo						2						Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50						А					
Forward Voltage (per element) @I _F =2.0A	V _{FM}		0.	55		0	.7	0	.85	0.	92	0.95	V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	I _{RM}	0.1 10			0.05 5				mA				
Typical Junction Capacitance(per leg) (Note 1)	CJ	28					pF						
Typical Thermal Resistance (per leg) (Note 2)	R _{0JL} 88			°C/W									
Operating and Storage Temperature Range	T _J , T _{STG}	G -55 to +150			°C								

Note: 1. V_R = 5V, T_C = 25 °C, f_{SIG} = 1MHz

2. mounted on P.C. Board with 5.0mm² copper pad areas.

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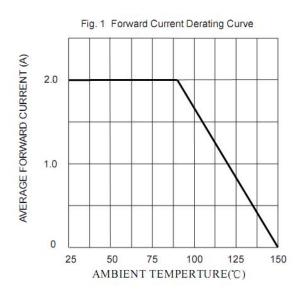
Circuit Diagram





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Ratings and Characteristics Curves



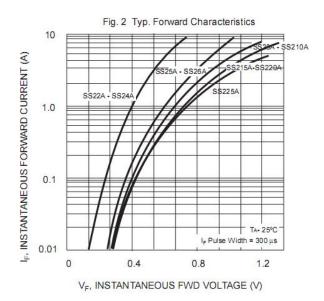
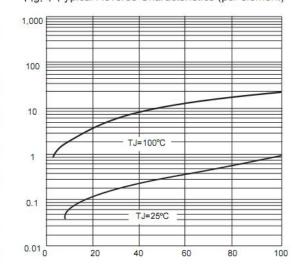


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

Fig. 4 Typical Reverse Characteristics (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

I_R, INSTANTANEOUS REVERSE CURRENT (μA)

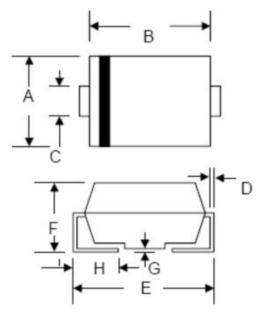


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Mechanical Dimensions SMA



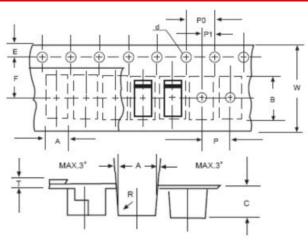
SYMBOL	Millin	neters	Inches			
STMBOL	Min.	Max.	Min.	Max.		
А	2.40	2.84	0.094	0.112		
В	3.99	4.75	0.157	0.187		
С	1.05	1.70	0.041	0.067		
D	0.15	0.51	0.006	0.020		
E	4.80	5.66	0.189	0.223		
F	1.90	2.95	0.075	0.116		
G	0.05	0.25	0.002	0.010		
н	0.76	1.52	0.030	0.600		

Ordering Information

Device	Package	Shipping			
SS22A - SS225A	SMA (Pb-Free)	5000pcs / reel			

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Carrier Tape Specification SMA





Marking Diagram

Where XXXXX is YYWWL

SS22A = Part Name = Year = Week = Lot Number

YΥ

L

WW

Cautions: Molding resin Epoxy resin UL:94V-0

SYMBOL	Millimeters					
STMBOL	Min.	Max.				
А	2.97	3.17				
В	5.70	5.90				
С	2.32	2.52				
d	1.40	1.60				
E	1.40	1.60				
F	5.60	5.70				
Р	3.90	4.10				
P0	3.90	4.10				
P1	1.90	2.10				
Т	0.25	0.35				
W	11.80	12.20				

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